EFC4621R

Power MOSFET 24V, 9A, 18mΩ N-Channel Dual EFCP



http://onsemi.com

Features

- 2.5V drive
- Common-drain type
- 2KV ESD HBM

- Protection diode in
- Halogen free compliance

Applications

• Lithium-ion battery charging and discharging switch

Specifications

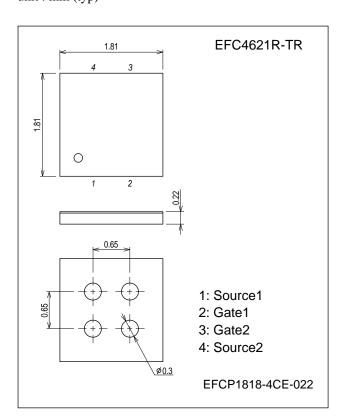
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Source to Source Voltage	VSSS		24	V	
Gate to Source Voltage	VGSS		±12	V	
Source Current (DC)	IS		9	Α	
Source Current (Pulse)	ISP	PW≤10μs, duty cycle≤1%	60	Α	
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.6	W	
Channel Temperature	Tch		150	°C	
Storage Temperature	Tstg		- 55 to +150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

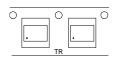
unit: mm (typ)



Ordering & Package Information

Device	Package	Shipping	note
EFC4621R-TR	EFCP	5000 pcs. / reel	Pb-Free and Halogen-Free

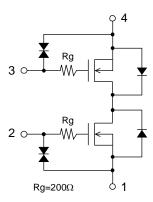
Packing Type: TR



Marking



Electrical Connection

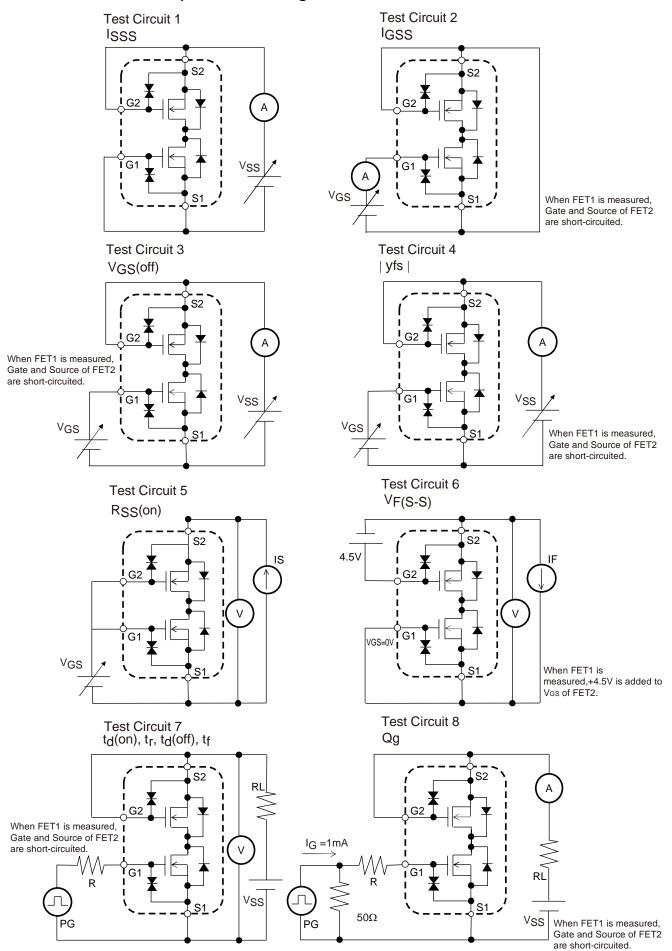


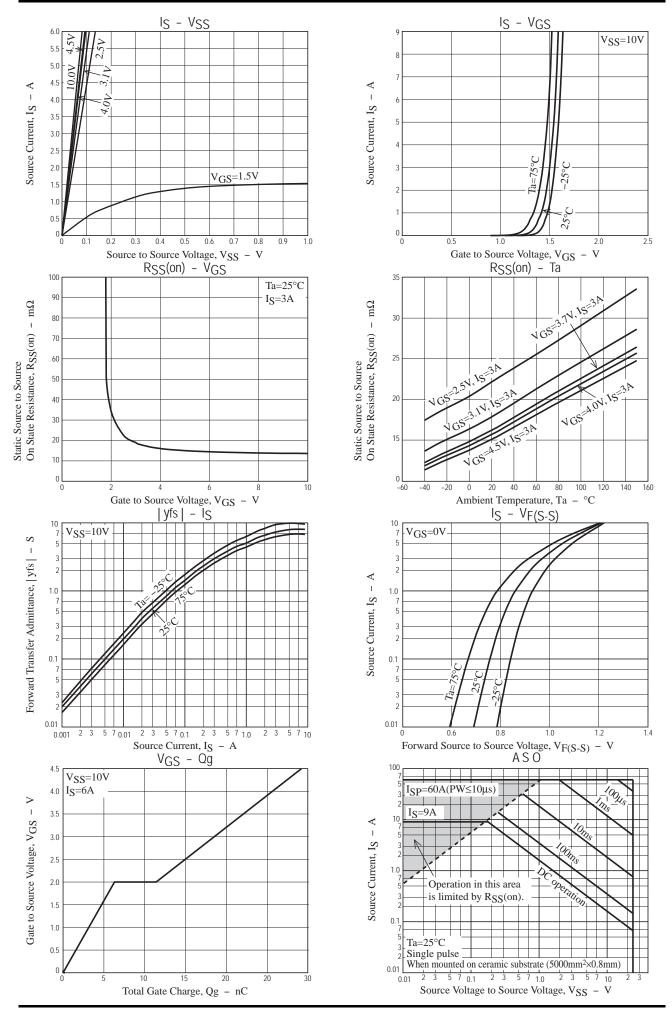
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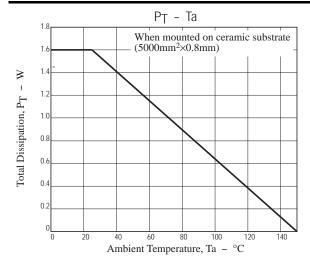
Electrical Characteristics at Ta = 25°C

		Conditions		Ratings			
Parameter	Symbol			min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	Test Circuit 1	24			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μА
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{SS} =0V	Test Circuit 2			±1	μА
Cutoff Voltage	V _{GS} (off)	V _{SS} =10V, I _S =1mA	Test Circuit 3	0.5		1.3	٧
Forward Transfer Admittance	yfs	V _{SS} =10V, I _S =3A	Test Circuit 4		7.3		S
	Rss(on)1	IS=3A, VGS=4.5V	Test Circuit 5	10.8	15.5	18	mΩ
	Rss(on)2	I _S =3A, V _{GS} =4.0V	Test Circuit 5	11.1	16	19	mΩ
Static Source to Source On-State Resistance	Rss(on)3	I _S =3A, V _G S=3.7V	Test Circuit 5	11.5	16.5	20	mΩ
	Rss(on)4	I _S =3A, V _G S=3.1V	Test Circuit 5	12.5	18	23.5	mΩ
	Rss(on)5	I _S =3A, V _{GS} =2.5V	Test Circuit 5	14.9	23	30	mΩ
Turn-ON Delay Time	t _d (on)				340		ns
Rise Time	t _r	<u> </u>			600		ns
Turn-OFF Delay Time	t _d (off)	VSS=10V, VGS=4.5V, IS=3A Test Circuit 7			26000		ns
Fall Time	tf				28000		ns
Total Gate Charge	Qg	V _{SS} =10V, V _{GS} =4.5V, I _S =	9A Test Circuit 8		29		nC
Forward Source to Source Voltage	VF(S-S)	I _S =3A, V _{GS} =0V	Test Circuit 6		0.77	1.2	٧

Test circuits are example of measuring FET1 side





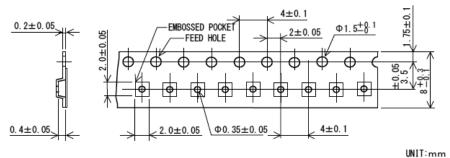


Taping Specification

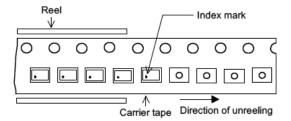
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1. Taping Configuration

1-1.Carrier Tape Size (unit:mm)

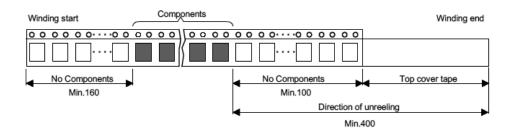


1-2. Device Placement Direction



Packing type \cdots TR

1-3 .Leader portion and Trailer portion (unit:mm)

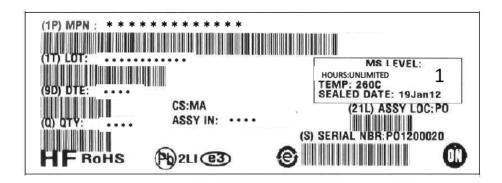


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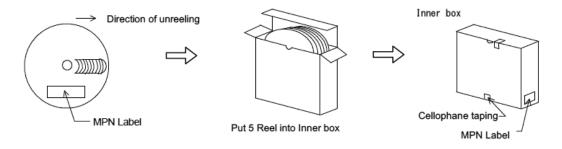
Packing Format

Carrier Tape code	Package code	Maximum Number of devices contained. (pcs.)		Packing Format		
		Reel	Inner box		Inner box BOX(C-1)	
2020X04	EFCP1818-4CE-022	5,000	25,000		5reels contained. Dimensions:mm 183×72×185	

MPN Label



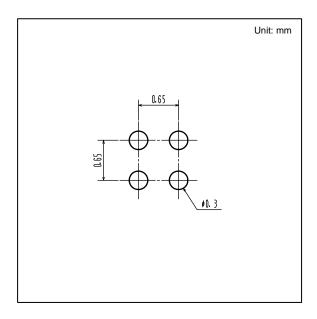
Packing Method



Outline Drawing

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Land Pattern Example



Note on usage: Since the EFC4621R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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